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# CLASS-E CURRENT-DRIVEN CENTER-TAPPED LOW $dv/dt$ RECTIFIER

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**Abstract** — An analysis for a Class E current-driven center-tapped low  $dv/dt$  rectifier taking into account the transformer leakage inductances is given along with experimental verifications. The rectifier diodes turn on and off at low  $dv/dt$ . This results in low switching noise and low switching losses. Diode parasitic capacitances do not adversely affect the circuit operation. The absolute value of  $di/dt$  is limited at diode turn-off, reducing the reverse recovery current. The circuit is operated at a low output voltage ripple and, therefore, at a low power loss in the equivalent series resistance (ESR) of the filter capacitor. Experimental tests were performed for a rectifier circuit operated at an output power of  $P_O = 60$  W, an minimum frequency of  $f = 500$  kHz, and an output voltage of  $V_O = 3.3$  V. The theoretical and the experimental results are in good agreement. Experimental measurements demonstrate that the rectifier is suitable for high-power density, high-frequency applications that requires low-output voltages and high-currents.

## I. INTRODUCTION

The increasing demand for small-volume light-weight power supplies has necessitated the development of high-frequency high-efficiency power converter circuits. This can be achieved if switching losses are eliminated. In class E rectifiers [1]–[7], zero-voltage turn on of the diode is achieved. Moreover, the diodes turn on and off at low  $dv/dt$  resulting in low switching noise. Therefore, these rectifiers can be operated at high switching frequencies with a nearly constant efficiency over a wide load range [4]–[6]. In the class E current-driven center-tapped rectifier, the output voltage ripple is drastically reduced, the average current through each diode is one-half of the output current, and a lower volume transformer than in the class E full-wave rectifier [7] can be used. As a result, the class E current-driven center-tapped rectifier is suitable for high power-density applications at high-output currents, e.g., higher than 10 A and low-output voltages, e.g., 3.3 V or 5 V, which are the standard supply voltages of advanced VLSI circuits. Moreover, Class E rectifiers can be used in combination with class D and class E resonant inverters to build high-frequency dc-dc converters [8]–[21].

The purpose of this paper is to present an analysis and experimental results for a class E current-driven center-tapped low  $dv/dt$  rectifier. The rectifier was tested on a 60 W power supply operated at a line ac voltage ranging from 75 to 275  $V_{rms}$ , an output current varying from 1.8 to 18 A, and an output voltage  $V_O = 3.3$  V regulated over the entire line voltage

and load current ranges. The nominal operating frequency of the converter circuit was  $f = 500$  kHz. A maximum efficiency  $\eta = 80\%$  was achieved for the entire power supply at the maximum load and an ac input voltage  $V_{I_{rms}} = 220$  V.

## II. CIRCUIT DESCRIPTION

A schematic circuit of the class E current-driven center-tapped low  $dv/dt$  rectifier and its model are shown in Figs. 1(a) and (b), respectively.

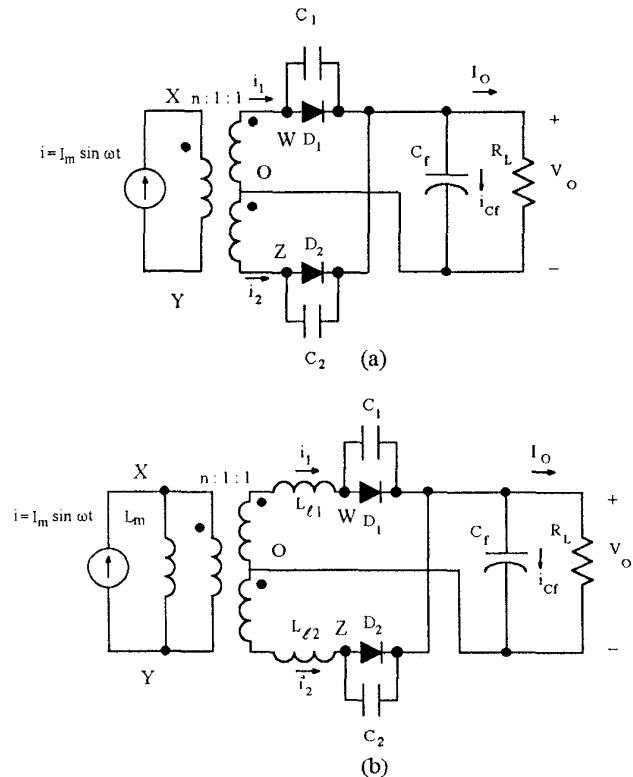


Fig. 1. Class E current-driven center-tapped low  $dv/dt$  rectifier. a) Schematic circuit. b) Model of the rectifier.

The rectifier consists of two diodes  $D_1$  and  $D_2$ , two capacitors  $C_1$  and  $C_2$ , a single-pole low-pass output filter  $C_f R_L$ , and a center-tapped transformer with a turns ratio  $n$ . Resistor  $R_L$  is the dc load resistance. The diode parasitic capacitances are absorbed into capacitances  $C_1$  and  $C_2$  connected in parallel with the diodes. The entire leakage flux of the transformer has been taken into account by means of two

leakage inductances  $L_{\ell 1}$  and  $L_{\ell 2}$  on the secondary side.  $L_m$  is the magnetizing inductance placed on the primary side of the transformer.

The transformer primary side is supplied by sinusoidal current source

$$i = I_m \sin \omega t \quad (1)$$

where  $I_m$  and  $\omega = 2\pi f$  are the amplitude and the angular frequency of the current, respectively.

### III. PRINCIPLE OF OPERATION

The rectifier circuit can be operated at an on duty cycle of each diode  $D$  ranging from 0 to 1 and goes through four topological configurations during one switching period  $T = 1/f$ . These topological modes are defined by the diode states as given in Table I.

TABLE I.  
RECTIFIER DIODE STATES.

	$D_1$	$D_2$
$0 < D \leq 0.5$		
$\phi \leq \omega t < \phi + 2\pi D$	ON	OFF
$\phi + 2\pi D \leq \omega t < \phi + \pi$	OFF	OFF
$\phi + \pi \leq \omega t < \phi + \pi + 2\pi D$	OFF	ON
$\phi + \pi + 2\pi D \leq \omega t < \phi + 2\pi$	OFF	OFF
$0.5 < D \leq 1$		
$\phi \leq \omega t < \phi + 2\pi D$	ON	OFF
$\phi + 2\pi D \leq \omega t < \phi + \pi$	ON	ON
$\phi + \pi \leq \omega t < \phi + \pi + 2\pi D$	OFF	ON
$\phi + \pi + 2\pi D \leq \omega t < \phi + 2\pi$	ON	ON

The current and voltage waveforms for the rectifier operated at  $0 < D \leq 0.5$  and  $0.5 < D \leq 1$  are shown in Figs. 2(a) and (b), respectively.

#### A. Operation for $0 < D \leq 0.5$

The first topological mode begins at  $\omega t = \phi$ , when voltage  $v_{D1}$  across diode  $D_1$  reaches zero turning diode  $D_1$  on. Actually,  $D_1$  turns on when  $v_{D1}$  reaches the threshold voltage  $V_T$ , e.g.,  $V_T = 0.4$  V for Schottky diodes. During this time interval, current  $i_1$  of the upper secondary winding flows through  $D_1$ . Diode  $D_2$  is off and its voltage waveform is shaped by the shunt capacitor  $C_2$ , according to  $i_{C2} = C_2 dv_{C2}/dt$ . The first mode ends at  $\omega t = \phi + 2\pi D$ , when current  $i_{D1}$  reaches zero, turning  $D_1$  off.

During the second topological mode both  $D_1$  and  $D_2$  are OFF. Current  $i_1$  flows through capacitor  $C_1$ , voltage  $v_{D1} = v_{C1}$  is shaped according to  $i_{C1} = C_1 dv_{C1}/dt$ . Since the capacitor current is zero at the beginning of the second topological mode, the derivative of  $v_{D1}$  is also zero at  $\omega t = \phi + 2\pi D$ . After diode  $D_1$  turn-off, voltage  $v_{D1}$  slowly decreases because  $i_{C1}$  is negative. Since  $i_{C2}$  is positive, voltage  $v_{D2}$  increases and reaches the diode threshold voltage at  $\omega t = \phi + \pi$ , turning diode  $D_2$  on. This ends the second mode.

The third topological mode begins at  $\omega t = \phi + \pi$ , when

diode  $D_2$  turns on and ends at  $\omega t = \phi + \pi + 2\pi D$ , when it turns off. During this time interval, the lower secondary winding current  $i_2$  flows through diode  $D_2$ . The waveform of the voltage across diode  $D_1$  and capacitor  $C_1$  is still shaped by the current through  $C_1$ . Therefore, it decreases, reaches its minimum value  $V_{DM}$  when  $i_{C1}$  is zero, and then increases when  $i_{C1}$  is positive.

The fourth mode begins, when current  $i_{D2}$  reaches zero and diode  $D_2$  turns off. As in the first topological mode,  $C_2$  shapes the voltage waveform of  $D_2$ . Therefore, voltage  $v_{D2}$  slowly decreases from zero because  $i_{C2}$  is zero at  $\omega t = \phi + \pi + 2\pi D$ . The current through capacitor  $C_1$  is positive and, therefore, voltage  $v_{D1}$  increases. Diode  $D_1$  turns on at  $\omega t = \phi + 2\pi$ , when  $v_{D1}$  reaches the threshold voltage. This ends the fourth topological mode and the switching period.

#### B. Operation for $0.5 < D \leq 1$

The first and the third topological modes are identical for the first and the third topological modes of the rectifier operated at  $0 < D \leq 0.5$ . The second topological mode begins at  $\omega t = \phi + \pi D$  when diode  $D_2$  turns on and ends at  $\omega t = \phi + 2\pi D$  when current  $i_1$  decreases to zero turning off diode  $D_1$ . The fourth topological modes begins at  $\omega t = \phi + \pi + 2\pi D$  when diode  $D_1$  turn on and ends at  $\omega t = \phi + 2\pi$  with the turn-off of diode  $D_2$ . During these two intervals both diodes are ON, terminals  $W$  and  $Z$  of the two secondary windings are shorted, and currents through these windings are  $i_1 = -i_2$ . The amplitudes of these current do not rise to dangerous values because the transformer primary side is driven by a current source.

### III. RECTIFIER CIRCUIT ANALYSIS

The analysis of the Class E rectifier of Fig. 1(a) begins with the following assumptions.

- 1) The rectifier circuit is symmetrical. Therefore,  $C_1 = C_2 = C_p$ , and  $L_{\ell 1} = L_{\ell 2} = L$ .
- 2) The parasitic resistances of the core and the windings, and the transformer stray capacitances are neglected.
- 3) The diodes are ideal and identical, i.e., they have zero threshold voltage, zero on-resistance, infinite off-resistance, and zero minority carrier charge lifetime in the case of the  $pn$  junction diode.
- 4) Filter capacitor  $C_f$  is large enough to neglect the output voltage ripple. For this reason, the parallel combination of  $C_f$  and  $R_L$  can be replaced by a dc voltage source.
- 5) The sinusoidal current source driving the primary side of the rectifier transformer is ideal.
- 6) The transformer has a turns ratio of  $n$  for each secondary. Moreover, the winding and core resistances and the stray capacitance of the transformer are ignored. The magnetizing inductance  $L_m$  is assumed to be large enough to carry only a dc current. Therefore, it can be considered as an open circuit for the ac component of the current.

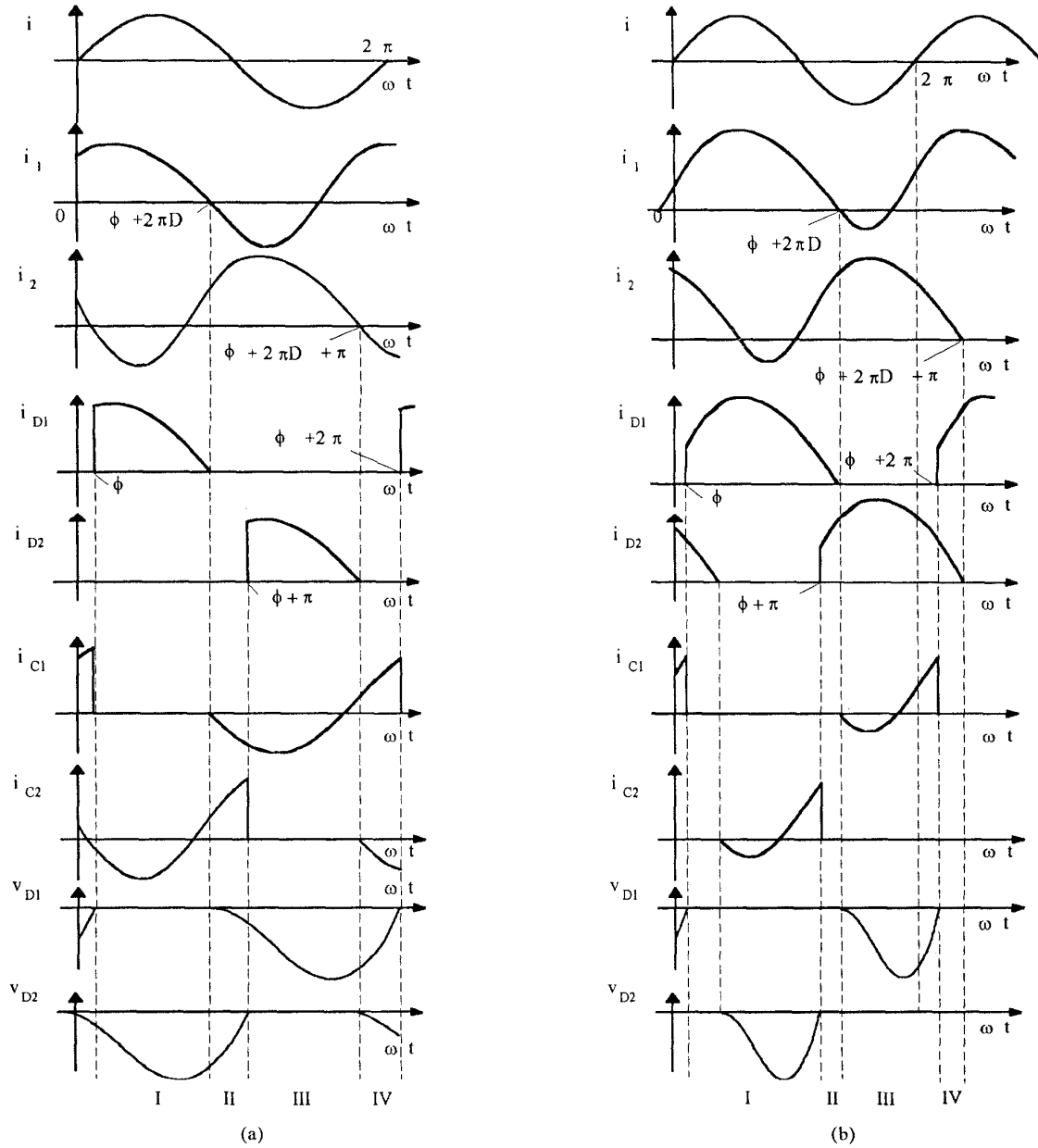


Fig. 2. Current and voltage waveforms in a class E current-driven center-tapped low  $dv/dt$  rectifier.  
a) Operation at  $0 < D \leq 0.5$ . b) Operation at  $0.5 < D \leq 1$ .

The equivalent circuits of the rectifier are linear during each interval given in Table I. Therefore, the Laplace transform can be used to analyze the rectifier circuit. Moreover, the relationship between the currents through the three transformer windings is given by

$$i(t) = \frac{1}{n} [i_1(t) - i_2(t)]. \quad (2)$$

Combinations of (1) and (2) with equations resulting from the analysis of the four equivalent circuits of the rectifiers during one switching period allows for the derivation of the current and voltage expressions. As an examples, the equations

of currents  $i_1$  and  $i_2$  and voltages  $v_{D1} = v_{C1}$  and  $v_{D2} = v_{C2}$  for each topological mode of a rectifier operated at  $0 < D \leq 0.5$  are given below.

A. First Topological Mode:  $\phi < \omega t \leq \phi + 2\pi D$

$$i_1 = nI_m \sin \omega t + \left\{ \cos \phi \left[ \omega^2 \sin(\omega t - \phi) - \frac{\omega \omega_o}{\sqrt{2}} \sin \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] \right] + \sin \phi \left[ \omega^2 \cos(\omega t - \phi) - \frac{\omega_o^2}{2} \cos \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] \right] \right\} + \frac{[i_1(\phi) + i_2(\phi)]}{2} \cos \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] - \frac{[2Vo + v_{C1}(\phi) + v_{C2}(\phi)]}{\sqrt{2}\omega_o L} \sin \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] \quad (3)$$

$$i_2 = \frac{nI_m}{(\omega_o^2 - 2\omega^2)} \times \left\{ \cos \phi \left[ \omega^2 \sin(\omega t - \phi) - \frac{\omega \omega_o}{\sqrt{2}} \sin \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] \right] + \sin \phi \left[ \omega^2 \cos(\omega t - \phi) - \frac{\omega_o^2}{2} \cos \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] \right] \right\} + \frac{i_1(\phi) + i_2(\phi)}{2} \cos \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] - \frac{2Vo + v_{C1}(\phi) + v_{C2}(\phi)}{\sqrt{2}\omega_o L} \sin \left[ \frac{\omega_o}{\sqrt{2}} \left( t - \frac{\phi}{\omega} \right) \right] \quad (4)$$

$$v_{C1} = 0 \quad (5)$$

$$v_{C2} = \frac{nI_m}{(\omega_o^2 - 2\omega^2)C} \times \left\{ -\omega \cos \phi \left[ \cos(\omega t - \phi) - \cos \left( \frac{1}{\sqrt{2}} \left( \frac{\omega_o t}{\omega} - \phi \right) \right) \right] + \sin \phi \left[ \omega \sin(\omega t - \phi) - \frac{\omega_o}{\sqrt{2}} \sin \left( \frac{1}{\sqrt{2}} \left( \frac{\omega_o t}{\omega} - \phi \right) \right) \right] \right\} + \frac{[i_1(\phi) + i_2(\phi)]}{2\omega_o C} \sin \left( \frac{1}{\sqrt{2}} \left( \frac{\omega_o t}{\omega} - \phi \right) \right) + [v_{C1}(\phi) + v_{C1}(\phi) + 2Vo] \left[ \cos \left( \frac{1}{\sqrt{2}} \left( \frac{\omega_o t}{\omega} - \phi \right) \right) - 1 \right] + v_{C2}(\phi) \quad (6)$$

B. Second Topological Mode:  $\phi + 2\pi D \leq \omega t \leq \phi + \pi$

$$i_1 = n \frac{I_m}{2} \sin \omega t + \frac{1}{2} [i_1(\phi + 2\pi D) + i_2(\phi + 2\pi D)] \times \cos \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] - \frac{[v_{C1}(\phi + 2\pi D) + v_{C2}(\phi + 2\pi D) + 2Vo]}{2\omega_o L} \times \sin \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] \quad (7)$$

$$i_2 = -n \frac{I_m}{2} \sin \omega t + \frac{1}{2} [i_1(\phi + 2\pi D) + i_2(\phi + 2\pi D)] \times \cos \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] - \frac{[v_{C1}(\phi + 2\pi D) + v_{C2}(\phi + 2\pi D) + 2Vo]}{2\omega_o L} \times \sin \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] \quad (8)$$

$$v_{C1} = nI_m \frac{\cos \omega t - 1}{2\omega C} + \frac{i_1(\phi + 2\pi D) + i_2(\phi + 2\pi D)}{2} \sin \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] + \frac{v_{C1}(\phi + 2\pi D)}{2} \cos \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] + \frac{v_{C1}(\phi + 2\pi D) + 2Vo}{2} \cos \left[ \omega_o \left( t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] - \frac{v_{C1}(\phi + 2\pi D) + v_{C2}(\phi + 2\pi D) + 2Vo}{2} + v_{C1}(\phi + 2\pi D) \quad (9)$$

C. Third Topological Mode:  $\phi + \pi < \omega t \leq \phi + \pi + 2\pi D$

$$\begin{aligned}
 i_1 = & -\frac{nI_m}{\omega_o^2 - 2\omega^2} \\
 & \times \left\{ \cos(\phi + \pi) \omega^2 \sin(\omega t - \phi - \pi) \right. \\
 & - \cos(\phi + \pi) \frac{\omega \omega_o}{\sqrt{2}} \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] + \\
 & + \sin(\phi + \pi) \left[ \omega^2 \cos(\omega t - \phi - \pi) \right. \\
 & + \left. \left. \frac{\omega_o^2}{2} \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \right] \right\} \\
 & + \frac{i_1(\phi + \pi) + i_2(\phi + \pi)}{2} \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \\
 & - \frac{2V_O + v_{C1}(\phi + \pi) + v_{C2}(\phi + \pi)}{\sqrt{2}\omega_o L} \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \quad (10)
 \end{aligned}$$

$$\begin{aligned}
 i_2 = & nI_m \sin \omega t \\
 & - \frac{nI_m}{\omega_o^2 - 2\omega^2} \left\{ \cos(\phi + \pi) \omega^2 \sin(\omega t - \phi - \pi) \right. \\
 & - \cos(\phi + \pi) \frac{\omega \omega_o}{\sqrt{2}} \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] + \\
 & + \sin(\phi + \pi) \left[ \omega^2 \cos(\omega t - \phi - \pi) \right. \\
 & - \left. \left. \frac{\omega_o^2}{2} \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \right] \right\} \\
 & + \frac{i_1(\phi + \pi) + i_2(\phi + \pi)}{2} \\
 & \times \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \\
 & - \frac{2V_O + v_{C1}(\phi + \pi) + v_{C2}(\phi + \pi)}{\sqrt{2}\omega_o L} \\
 & \times \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \quad (11)
 \end{aligned}$$

$$v_{C2} = 0 \quad (12)$$

$$\begin{aligned}
 v_{C1} = & -\frac{nI_m}{C(\omega_o^2 - 2\omega^2)} \\
 & \times \left\{ -\omega \cos(\phi + \pi) \cos(\omega t - \phi - \pi) \right. \\
 & + \omega \cos(\phi + \pi) \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \\
 & + \sin(\phi + \pi) \left[ \omega \sin(\omega t - \phi - \pi) \right. \\
 & - \left. \left. \frac{\omega_o}{\sqrt{2}} \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \right] \right\} \\
 & + \frac{i_1(\phi + \pi) + i_2(\phi + \pi)}{2\omega_o C} \\
 & \times \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] + \\
 & + [v_{C1}(\phi + \pi) + v_{C2}(\phi + \pi) + 2V_O] \\
 & \times \left[ \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] - 1 \right] + v_{C1}(\phi + \pi) \quad (13)
 \end{aligned}$$

D. Fourth Topological Mode:  $\phi + \pi + 2\pi D < \omega t \leq \phi + 2\pi$

$$\begin{aligned}
 i_1 = & n \frac{I_m}{2} \sin \omega t \\
 & + \frac{1}{2} [i_1(\phi + 2\pi D + \pi)] \cos\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \\
 & + \frac{1}{2} [i_2(\phi + 2\pi D + \pi)] \cos\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \\
 & - \frac{v_{C1}(\phi + 2\pi D + \pi)}{(2\omega_o L)} \sin\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \\
 & - \frac{v_{C2}(\phi + 2\pi D + \pi) + 2V_O}{2\omega_o L} \sin\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \quad (14)
 \end{aligned}$$

$$\begin{aligned}
 i_2 = & -n \frac{I_m}{2} \sin(\omega t) \\
 & + \frac{1}{2} [i_1(\phi + 2\pi D + \pi)] \cos\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \\
 & + \frac{1}{2} [i_2(\phi + 2\pi D + \pi)] \cos\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \\
 & - \frac{v_{C1}(\phi + 2\pi D + \pi)}{2\omega_o L} \sin\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \\
 & - \frac{v_{C2}(\phi + 2\pi D + \pi) + 2V_O}{2\omega_o L} \sin\left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega}\right)\right] \quad (15)
 \end{aligned}$$

$$\begin{aligned}
v_{C1} = & -nI_m \frac{\cos \omega t - 1}{2\omega C} \\
& + \frac{i_1 (\phi + 2\pi D + \pi)}{2} \sin \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\
& + \frac{i_2 (\phi + 2\pi D + \pi)}{2} \sin \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] + \\
& + \frac{v_{C1} (\phi + 2\pi D + \pi)}{2} \cos \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\
& + \frac{v_{C2} (\phi + 2\pi D + \pi)}{2} \cos \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\
& + V_o \cos \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] + v_{C1} (\phi + 2\pi D + \pi) \\
& - \frac{v_{C1} (\phi + 2\pi D + \pi) + v_{C2} (\phi + 2\pi D + \pi) + 2V_o}{2}
\end{aligned} \tag{16}$$

$$\begin{aligned}
v_{C2} = & nI_m \frac{\cos \omega t - 1}{2\omega C} \\
& + \frac{i_1 (\phi + 2\pi D + \pi)}{2} \sin \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\
& + \frac{i_2 (\phi + 2\pi D + \pi)}{2} \sin \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\
& + \frac{v_{C1} (\phi + 2\pi D + \pi)}{2} \left\{ \cos \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - 1 \right\} \\
& + \frac{v_{C2} (\phi + 2\pi D + \pi)}{2} \left\{ \cos \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - 1 \right\} \\
& + V_o \left\{ \cos \left[ \omega_o \left( t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - 1 \right\} \\
& + v_{C2} (\phi + 2\pi D + \pi)
\end{aligned} \tag{17}$$

where  $\omega_o = 1/\sqrt{LC}$ .

Combination of (1) to (17) allows for the calculation of parameters such as  $\phi$ ,  $D$ , the dc output current  $I_o$ , the maximum current through each diode  $I_{DM}$ , and the maximum reverse voltage across each diode  $V_{DM}$ . Unfortunately, the expressions of these quantities cannot be derived in a closed form. For this reason, a computer program has been developed to calculate these parameters.

Fig. 3 shows a plot of  $D$  as a function of load resistance  $R_L$  for  $f_o = 4.9$  MHz (resulting from  $L = 15$  nH and  $C_p = 70$  nF) and a constant output voltage normalized with respect to the transformer turns ratio  $V_o/n = 0.275$  (it has been assumed that  $V_o = 3.3$  V and  $n = 12$ ). The diode duty cycle decreases as the output current decreases. Therefore, the current through the diodes becomes more impulsive at light loads. Moreover, a small variation of  $D$  is needed to regulate the output voltage over a wide load range, e.g., duty cycle  $D$  decreases from 0.6 to 0.45 for a load resistance increasing from 0.14  $\Omega$  to 1.4  $\Omega$ .

Figs. 4 depicts a plot of the maximum current through the

transformer primary winding  $I_m$  of  $R_L$  at  $f_o = 4.9$  MHz and  $V_o/n = 0.27$ . Current  $I_m$  increases from 0.5 A to 5 A as the dc output current  $I_o$  increases from 2.3 A to 23 A. Therefore, both the dc output current and the primary current range in the same relative interval, e.g., 1 to 10 or 10% to 100%.

Both  $I_m$  and  $D$  depend on  $\omega_o$  and  $V_o/n$  while the diode maximum current and voltage are independent of these parameters.

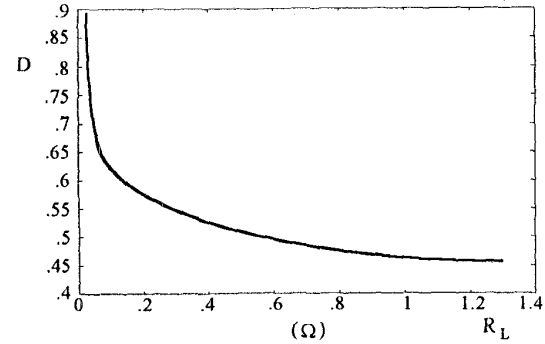


Fig. 3. Duty cycle  $D$  versus load resistance  $R_L$ .

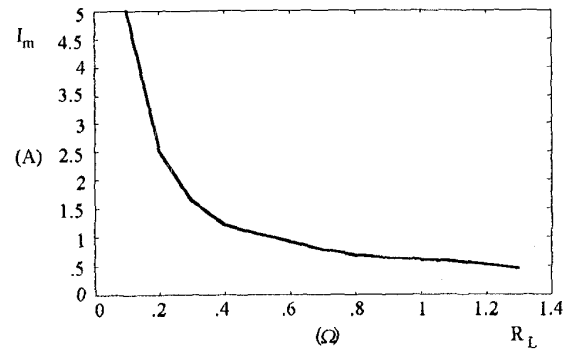


Fig. 4. Amplitude of primary current  $I_m$  as a function of  $R_L$  at  $f_o = 4.9$  MHz and  $V_o/n = 0.27$ .

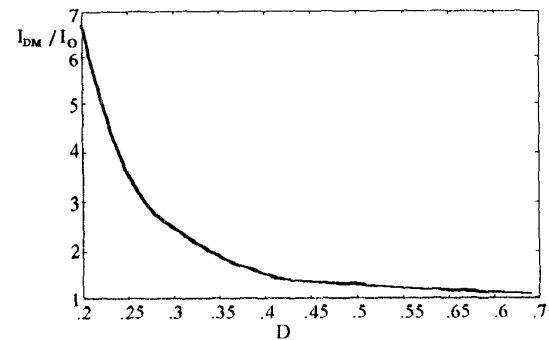


Fig. 5. Normalized maximum current  $I_{DM}/I_o$  as a function of duty cycle  $D$ .

Fig. 5 shows  $I_{DM}$  normalized with respect to  $I_o$  as a function of  $D$ . The maximum normalized current through the diodes decreases from 1.5 to 1.1 as  $D$  increases from 0.4 to 0.6. Since  $D$  is in the range of 0.45–0.6 for a load resistance decreasing from 1.4 to 0.14, the maximum current through the diodes increases from 3.45 to 25 A for a dc output current

ranging from 2.3 to 23 A. This shows that the current through the diodes does not significantly exceeds the dc output current when the rectifier is operated at full load.

A plot of  $V_{DM}$  normalized with respect to  $V_O$  as a function of  $D$  is shown in Fig. 6. The maximum normalized reverse voltage across the rectifier diodes increases from 3.5 to 4.3 for  $D$  increasing from 0.45 to 0.6. For a rectifier operated at an output voltage  $V_O = 3.3$  V and a load resistance in the range to 0.14 to 14  $\Omega$ , the maximum voltage across the diodes increases from 11.5 V at full load to 14.2 V at light load. Because of the low values of  $V_{DM}$ , Schottky diodes can be used in the rectifier circuits. This allows for a high-frequency operation of the rectifier.

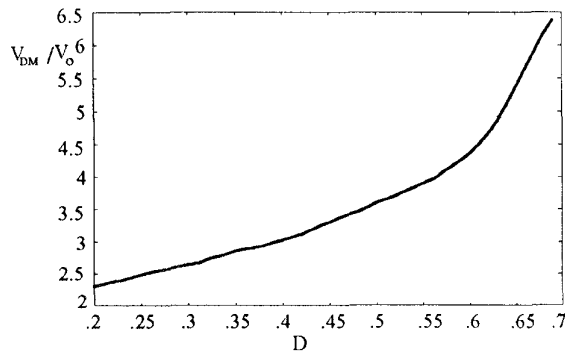


Fig. 5. Normalized maximum diode reverse voltage  $V_{DM}/V_O$  as a function of duty cycle  $D$ .

#### IV. DESIGN EXAMPLE AND EXPERIMENTAL RESULTS

A full-range off-line power supply based on class DE dc-dc converter with a class D series resonant inverter and a class E current-driven center-tapped low  $dv/dt$  rectifier was built to operate at an input dc voltage  $V_I = 120$  to  $370$  V<sub>dc</sub>, a regulated output voltage  $V_O = 3.3$  V, an output power  $P_O = 60$  W, and a nominal operating frequency  $f = 500$  kHz. The maximum output current of the converter was  $I_{OM} = 18$  A, which corresponds to a minimum load resistance  $R_{L,min} = 0.18 \Omega$ . The converter circuit was designed for the minimum input voltage and maximum load operation. The dc-to-dc voltage transfer function of the entire converter was  $M_{max} = V_O / V_{Imin} = 3.3 / 120 = 0.0275$ . A class D series resonant inverter operated at a voltage transfer function  $M_{Imax} = 0.383$  was used as a sinusoidal current source. Therefore, the rectifier voltage transfer function was  $M_R = M_{max} / M_{Imax} = 0.0275 / 0.383 = 0.072$ . As a result, the amplitude of the fundamental component of the primary winding voltage in phase with the primary current was calculated as  $V_{Rm} = \sqrt{2} V_O / M_R = 64.8$  V and the transformer turns ratio was  $n = 12$ .

The center-tapped transformer was built on a EFD30 Siemens N49 ferrite core. The primary was wound with 24 turns of AWG22 solid copper wire and the two secondary windings with 2 turns of copper strips  $15 \times 0.15$  mm each. The measured transformer magnetizing inductance was  $L_m = 1.23$  mH, the equivalent series resistance (ESR) of the three windings seen across the terminals of the primary winding was  $R_S = 0.63 \Omega$ ,  $f = 500$  kHz and each secondary

leakage inductance was  $L = 18$  nH. Two International Rectifier 32CTQ30 Schottky diodes were used in the rectifier. An external capacitance  $C_p = 66$  nF was connected in parallel with each diode. Two electrolytic Oscon  $100 \mu\text{F} / 20$  V capacitors connected in parallel were used as filter capacitors. Fig. 6 shows experimental voltage and current waveforms of the transformer primary winding at  $V_I = 110$  V and  $f = 465$  kHz. Fig. 7 shows the experimental waveforms of the voltages across diodes  $D_1$  and  $D_2$ . The measured efficiency of the ac-dc converter including the front-end full-bridge transformerless rectifier is plotted in Fig. 8 as a function of  $I_O$ . The measured efficiency at the full load operation at a low line voltage  $V_{I,rms} = 120$  V was  $\eta = 81\%$  and was 1.5% higher than the efficiency measured at  $V_{I,rms} = 220$  V over the entire load range.

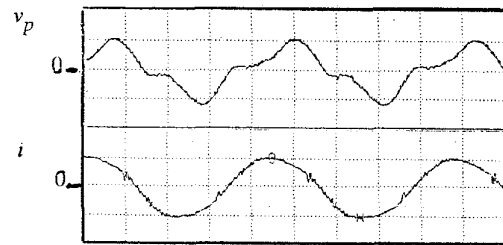


Fig. 6. Waveforms of voltage and current for the primary winding for the transformer at an operating frequency  $f = 465$  kHz, ac input voltage  $V_{I,rms} = 110$  V, output voltage  $V_O = 3.3$  V, and  $R_L = 0.18 \Omega$ . Vertical: 100 V/div. for  $v_p$  and 2 A/div. for  $i$ ; horizontal 500 ns/div.

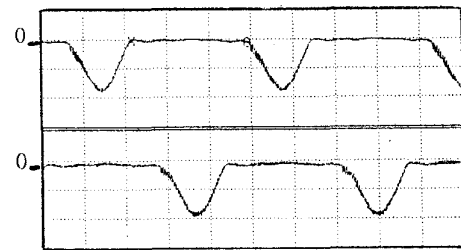


Fig. 7. Waveforms of the reverse voltage on each diode at an operating frequency  $f = 465$  kHz, ac input voltage  $V_{I,rms} = 110$  V, output voltage  $V_O = 3.3$  V, and  $R_L = 0.18 \Omega$ . Vertical: 10 V/div.; horizontal 500 ns/div.

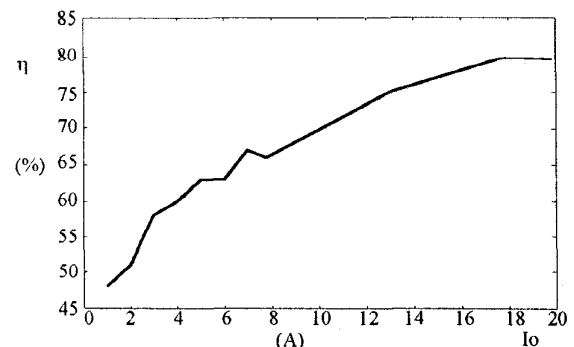


Fig. 8. Efficiency of the entire power supply versus output current at an ac input voltage  $V_{I,rms} = 220$  V and  $V_O = 3.3$  V.



## V. CONCLUSIONS

The analysis, design procedure, and experimental verification of a class E current-driven center-tapped low  $dv/dt$  rectifier have been presented. The leakage inductances of the transformer have been taken into account. In the class E rectifier, each diode turns on and off at zero voltage with a limited  $dv/dt$  at the turn-off and  $dv/dt = 0$  at the turn-on. Moreover,  $di/dt$  is limited at the diode turn-off and a soft-reverse recovery of diodes is achieved. The class E current-driven center-tapped low  $dv/dt$  rectifier has been used to build a 60 W power supply operated at a line voltage varying from 85 to 260 V<sub>rms</sub> and a regulated output voltage  $V_O = 3.3$  V. A maximum efficiency  $\eta = 80\%$  has been achieved for the whole power supply at the maximum output current  $I_O = 18$  A and input ac voltage  $V_{rms} = 220$  V.

Since zero-voltage turn-on of the switches is achieved, the rectifier efficiency can be increased if diodes are replaced by low on-resistance power MOSFETs. Theoretical analysis and experimental verifications of the class E current-driven center-tapped synchronous rectifier are recommended for future work.

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